

2.4 ROTALED2 - Version 2 avec BP et ajustable

Projet : IUT6

Info : [DIV538]

Révision : 1 du 8 janvier 2008

Révision : 2 du 13 janvier 2008

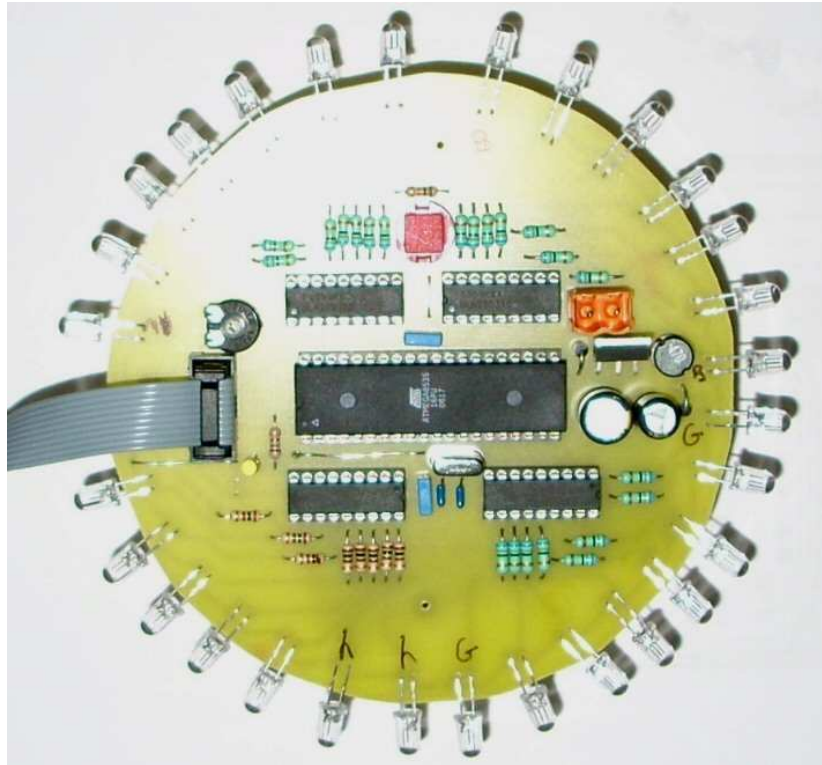


Figure 2.2. Vue de carte électronique (images-maquettes\ROTALED2-12.jpg).

2.5 Calculs des composants

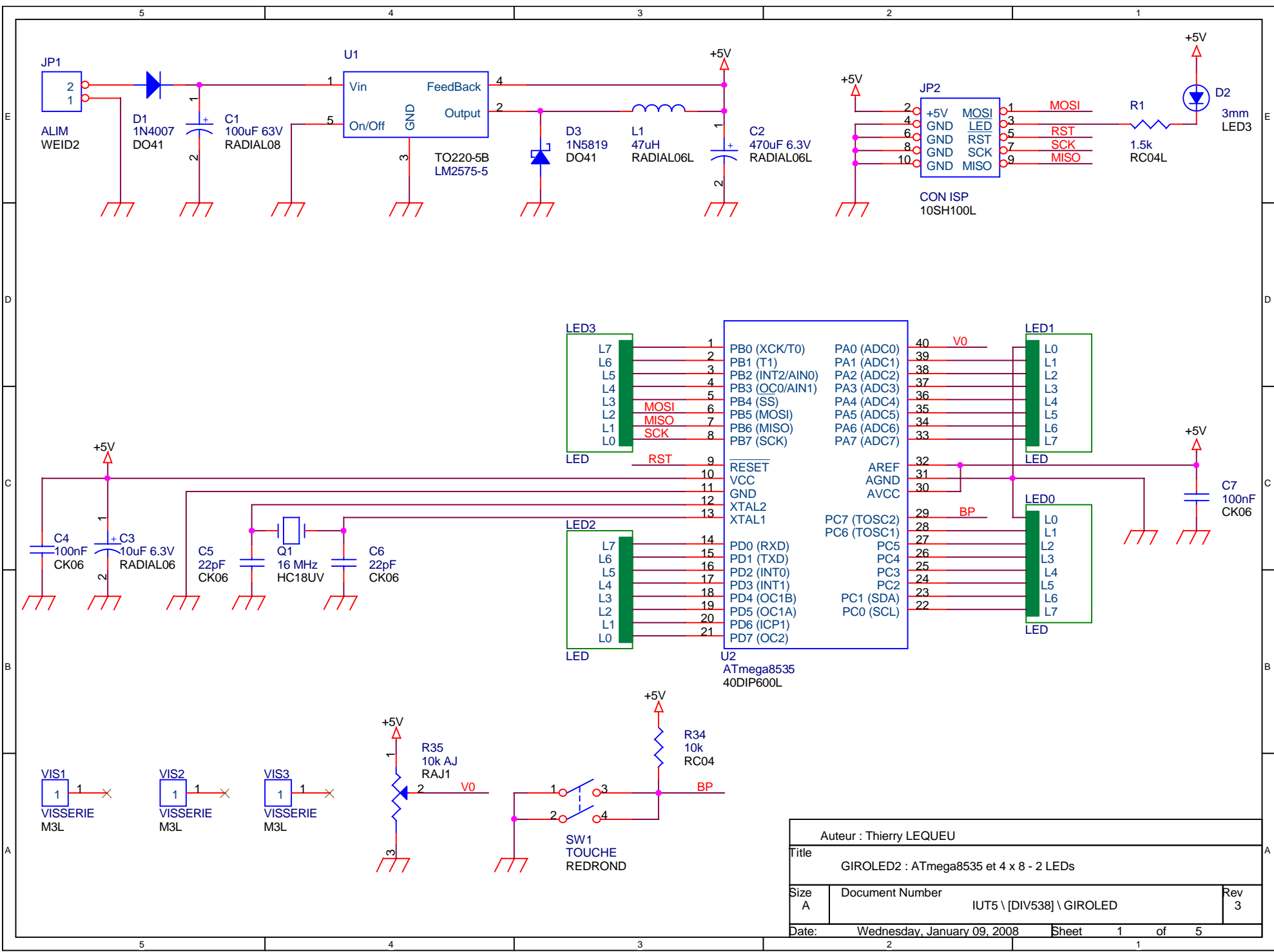
Tableau 2.3. Liste de composants (Calculs-Composants.xls / 10000mcd).

Size	Couleur	Candela	Vmin	Vmax	IF	Valim	Vce sat	Rmax	Rmin	Retenu	Puissance
		k mcd	Volt	Volt	Amp.	Volt	Volt	Ohms	Ohms	Ohms	Watt
5 mm	Yellow	10-15	1,9	2,5	0,015	5	0,2	193,3	153,3	160	0,036
5 mm	Green	10-15	2,9	3,5	0,015	5	0,2	126,7	86,7	100	0,0225
5 mm	Blue	6-9	2,9	3,5	0,015	5	0,2	126,7	86,7	100	0,0225
5 mm	White	12-18	2,9	3,5	0,015	5	0,2	126,7	86,7	100	0,0225
10 mm	Red		1,9	2,5	0,025	5	0,2	116,0	92,0	120	0,075

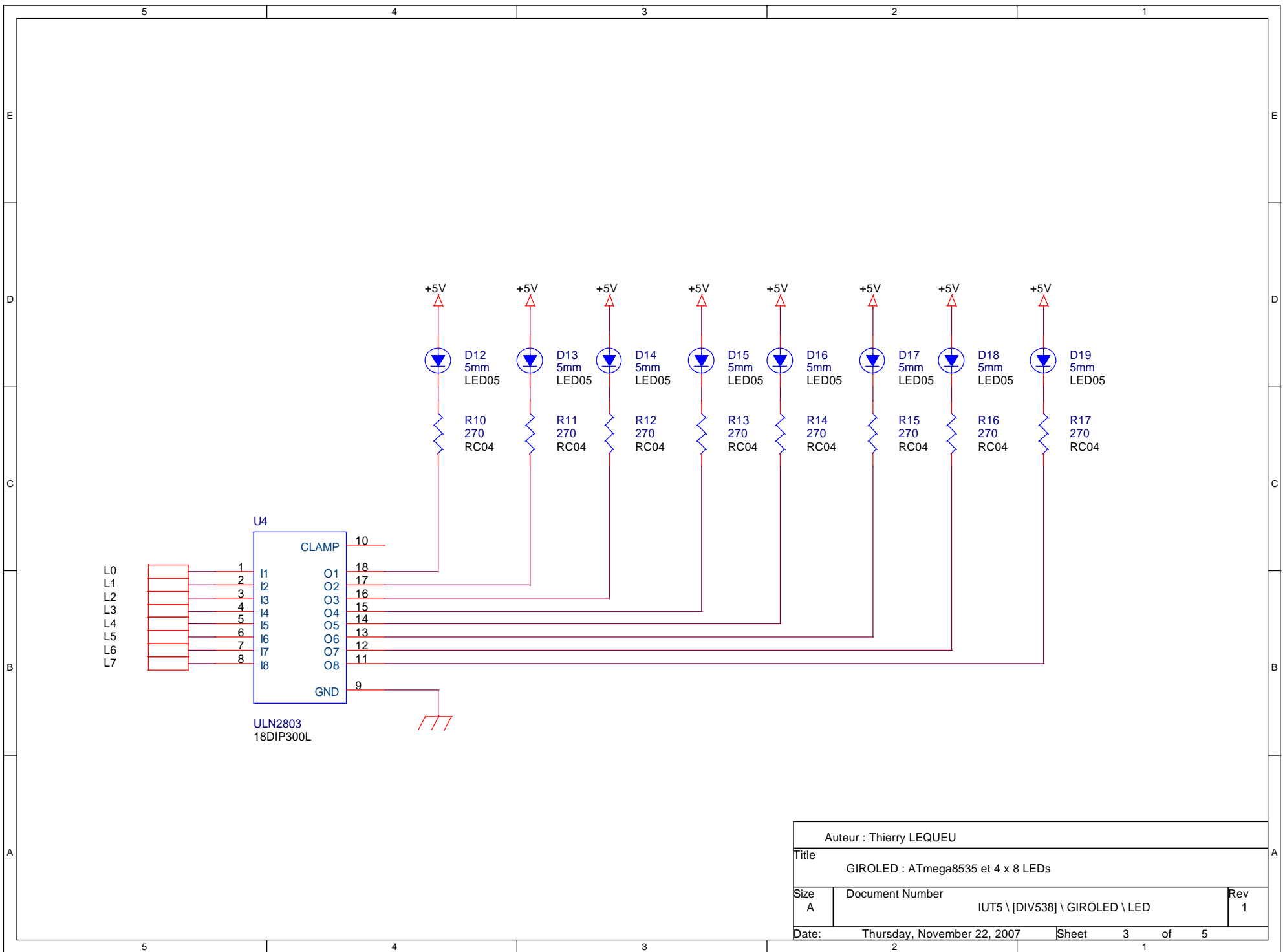
ROTALED2 : ATmega8535 et 4 x 8 LEDs**Revised: Wednesday, January 09, 2008****IUT5 \ [DIV538] \ ROTALED2 Revision: 3**

Référence	Qu.	Désignation	Fournisseur	Code Cde.	U.d.V.	Prix U.H.T.	Prix T.H.T.
C1	1	100uF 63V FC	Radiospares	315-0962	5	2,05 €	0,410 €
C2	1	470uF 6.3V FC	Radiospares	449-0845	5	1,21 €	0,242 €
C3	1	10uF 50V FC	Radiospares	315-0805	5	0,97 €	0,194 €
C4,C7	2	100nF 63V MKT	Radiospares	537-3044	10	1,36 €	0,272 €
C6,C5	2	22pF Céramique	Radiospares	405-7612	10	1,03 €	0,206 €
D1	1	1N4007	Radiospares	348-5397	1	0,13 €	0,130 €
D2	1	LED jaune 3mm 2mA	Radiospares	171-1228	10	3,44 €	0,344 €
D3	1	1N5819	Radiospares	544-4994	5	1,10 €	0,220 €
D4,...D35	32	LED 10mm 20mA	Asso e-Kart		1	0,75 €	24,000 €
JP1	1	Connecteur 2 points Weidmuller	Radiospares	403-932	5	2,02 €	0,404 €
JP2	1	CON ISP	Radiospares	461-742	1	1,82 €	1,820 €
L1	1	47uH 0,5A	Radiospares	432-4394	10	12,93 €	1,293 €
Q1	1	Quartz 16 MHz	Radiospares	226-1825	1	0,64 €	0,640 €
R1	1	1.5k 0,25W	IUT GEII		1	0,01 €	0,010 €
R2,...,R33	32	120 0,25W	IUT GEII		1	0,01 €	0,320 €
U1	1	LM2575T-5.0	Radiospares	534-2545	45	106,09 €	2,358 €
U2	1	ATmega8535	FARNELL	917-1444	1	1,80 €	1,800 €
U3,U4,U5,U6	4	ULN2803	Radiospares	646-6311	5	2,97 €	2,376 €
VIS2,VIS1	2	VISSERIE	IUT GEII		2	0,05 €	0,050 €
Divers	170	Circuit imprimé SF 130x130 mm	Radiospares	159-6120	600	15,95 €	4,519 €

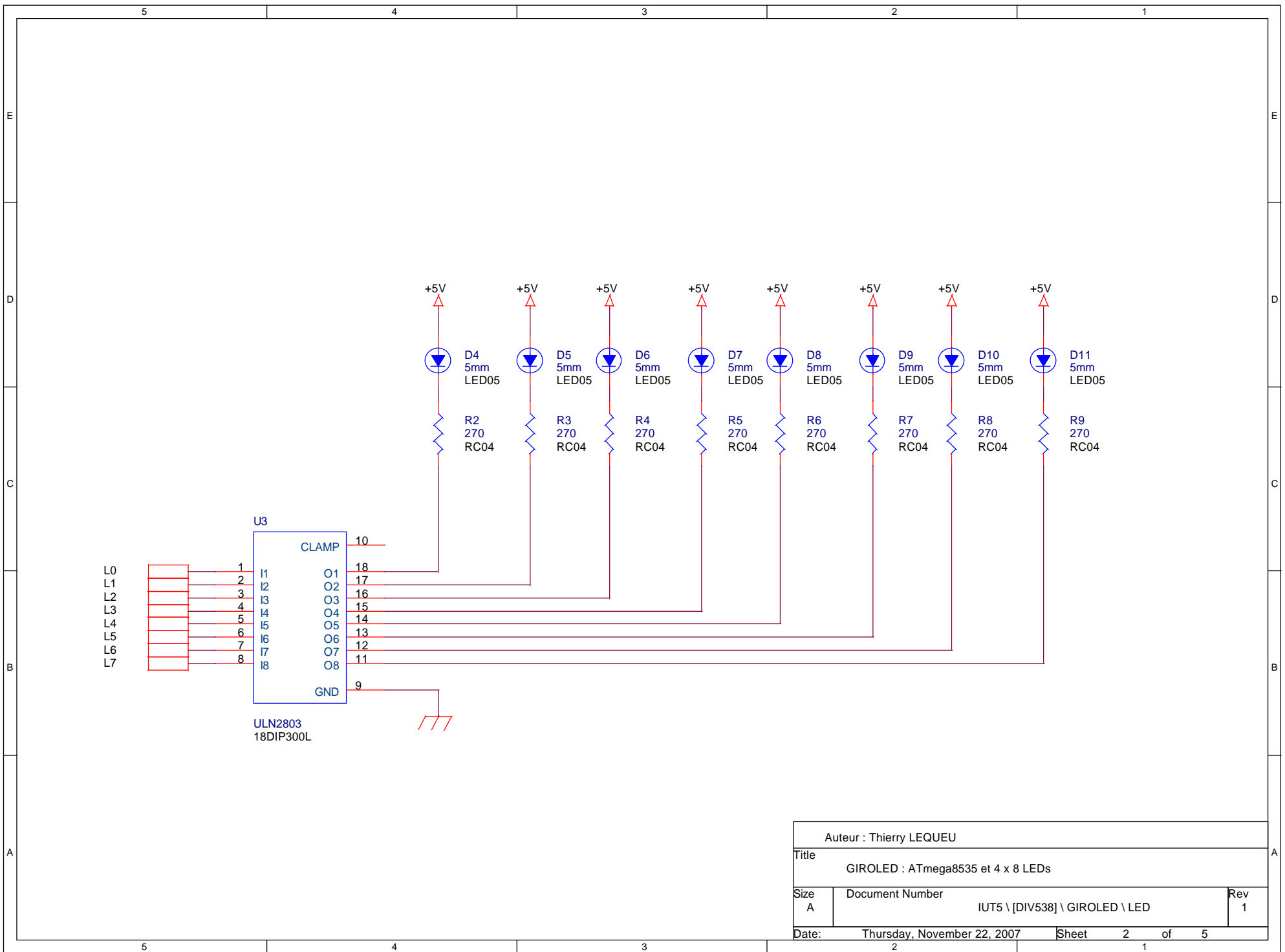
TOTAL H.T. :	41,61 €
dont TVA : 19,60%	8,16 €
TOTAL T.T.C. :	49,77 €



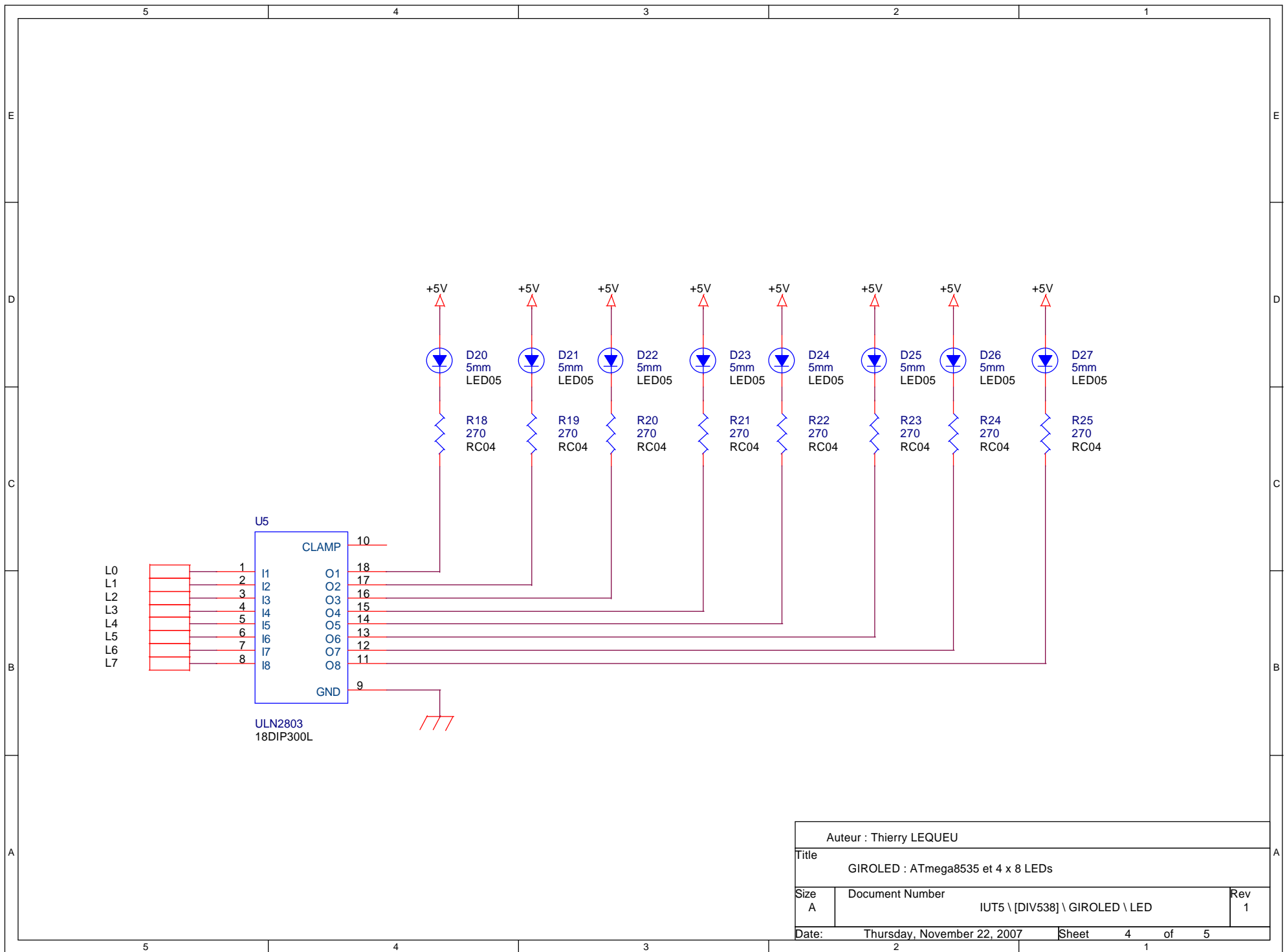
Auteur : Thierry LEQUEU		
Title GIROLED2 : ATmega8535 et 4 x 8 - 2 LEDs		
Size A	Document Number IUT5 \ [DIV538] \ GIROLED	Rev 3
Date:	Wednesday, January 09, 2008	Sheet 1 of 5



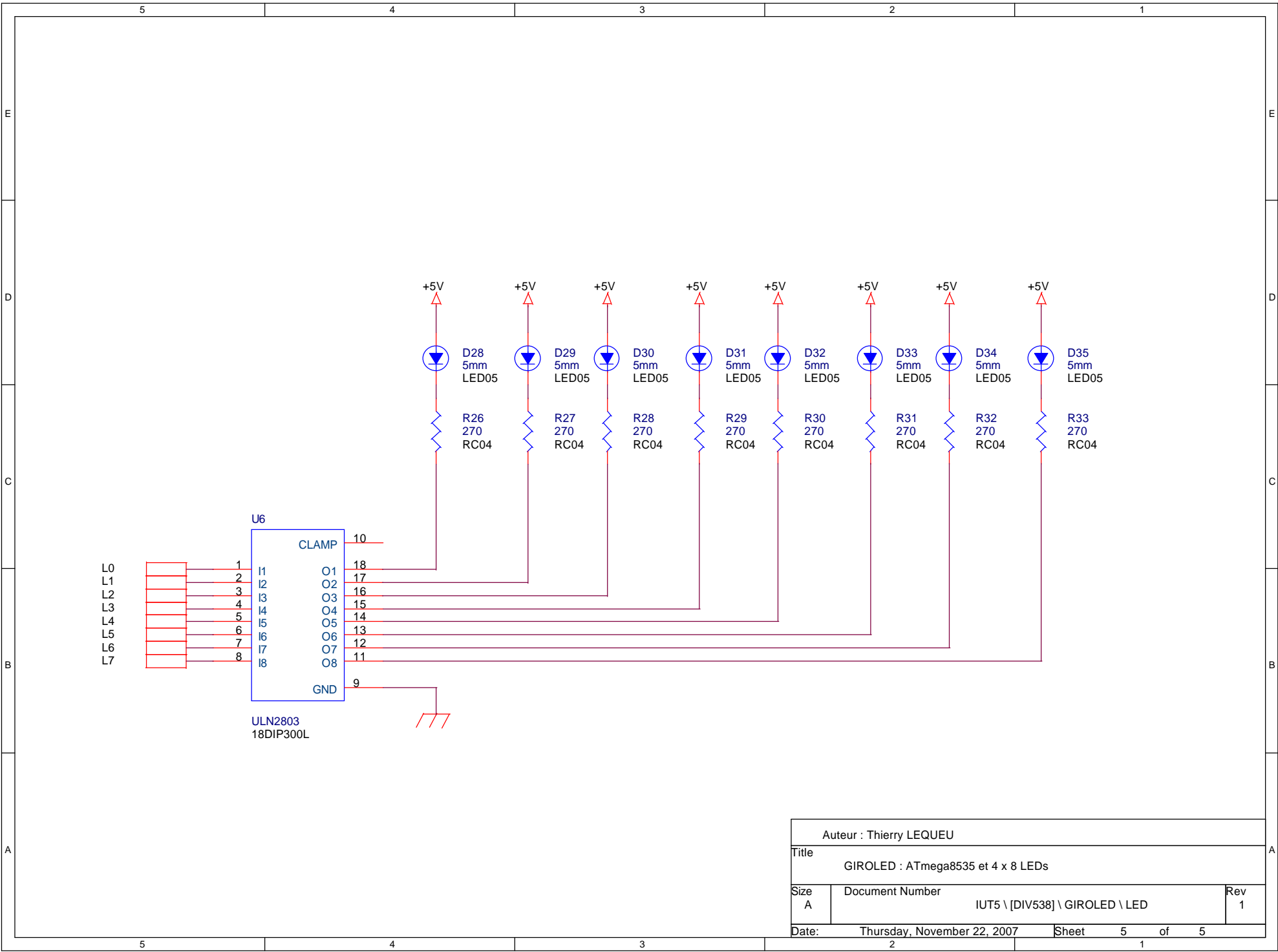
Auteur : Thierry LEQUEU		
Title GIROLED : ATmega8535 et 4 x 8 LEDs		
Size A	Document Number IUT5 \ [DIV538] \ GIROLED \ LED	Rev 1
Date:	Thursday, November 22, 2007	Sheet 3 of 5



Auteur : Thierry LEQUEU		
Title GIROLED : ATmega8535 et 4 x 8 LEDs		
Size A	Document Number IUT5 \ [DIV538] \ GIROLED \ LED	Rev 1
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Auteur : Thierry LEQUEU		
Title GIROLED : ATmega8535 et 4 x 8 LEDs		
Size A	Document Number IUT5 \ [DIV538] \ GIROLED \ LED	Rev 1
Date:	Thursday, November 22, 2007	Sheet 4 of 5



L0
L1
L2
L3
L4
L5
L6
L7

U6
ULN2803
18DIP300L

CLAMP 10
O1 18
O2 17
O3 16
O4 15
O5 14
O6 13
O7 12
O8 11
GND 9

+5V

D28 5mm LED05
R26 270 RC04

D29 5mm LED05
R27 270 RC04

D30 5mm LED05
R28 270 RC04

D31 5mm LED05
R29 270 RC04

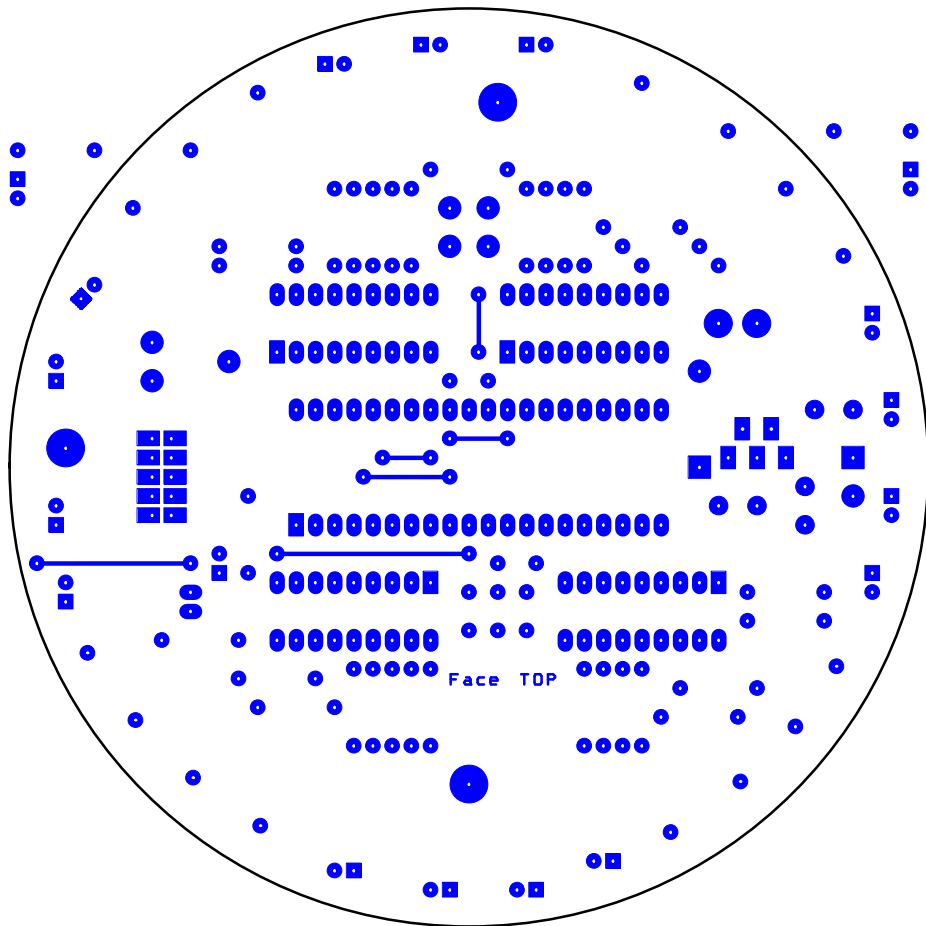
D32 5mm LED05
R30 270 RC04

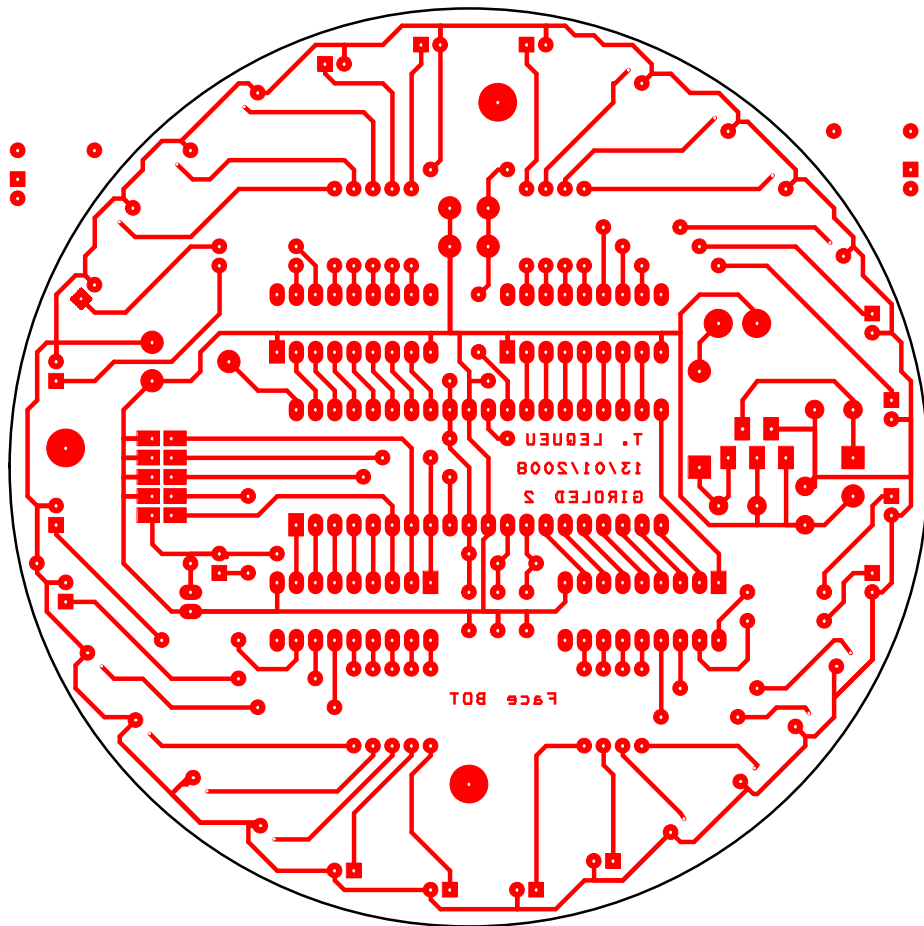
D33 5mm LED05
R31 270 RC04

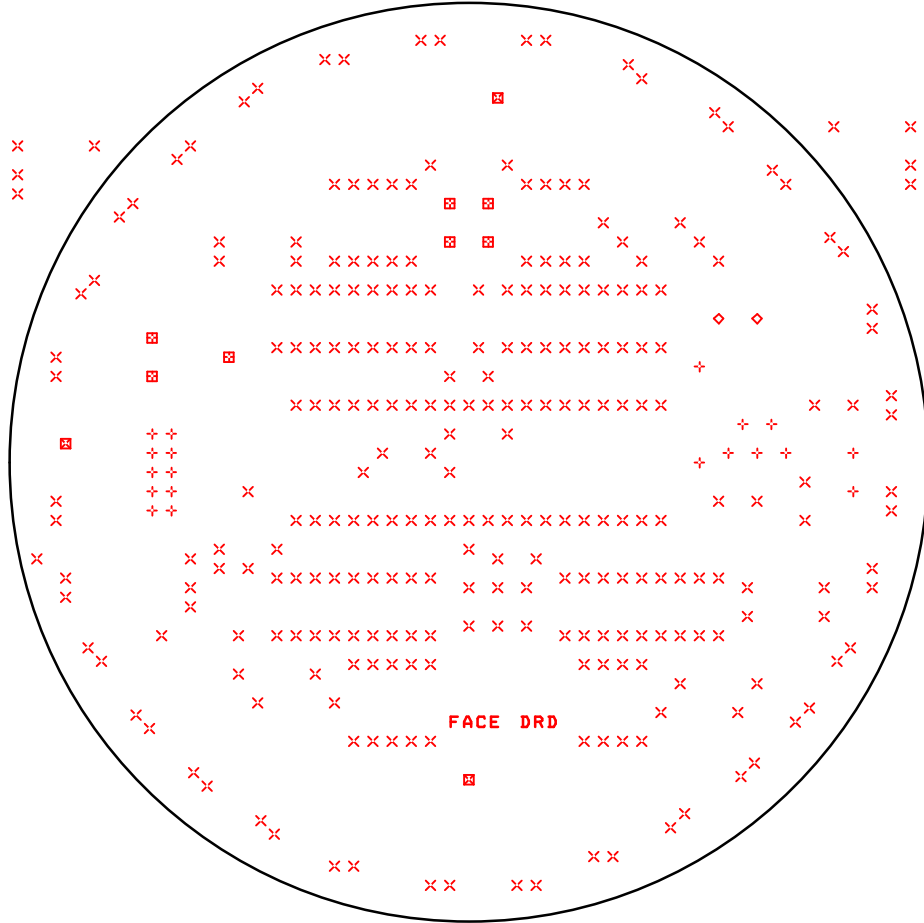
D34 5mm LED05
R32 270 RC04

D35 5mm LED05
R33 270 RC04

Auteur : Thierry LEQUEU		
Title GIROLED : ATmega8535 et 4 x 8 LEDs		
Size A	Document Number IUT5 \ [DIV538] \ GIROLED \ LED	Rev 1
Date:	Thursday, November 22, 2007	Sheet 5 of 5







DRILL CHART				
SYM	DIAM	TOL	QTY	NOTE
x	0.787 mm		276	
+	0.991 mm		19	
◇	1.000 mm		2	
⊠	1.194 mm		7	
⊞	1.499 mm		3	
TOTAL			307	

Features

- High-performance, Low-power AVR[®] 8-bit Microcontroller
- Advanced RISC Architecture
 - 130 Powerful Instructions – Most Single Clock Cycle Execution
 - 32 x 8 General Purpose Working Registers
 - Fully Static Operation
 - Up to 16 MIPS Throughput at 16 MHz
 - On-chip 2-cycle Multiplier
- Nonvolatile Program and Data Memories
 - 8K Bytes of In-System Self-Programmable Flash
 - Endurance: 10,000 Write/Erase Cycles
 - Optional Boot Code Section with Independent Lock Bits
 - In-System Programming by On-chip Boot Program
 - True Read-While-Write Operation
 - 512 Bytes EEPROM
 - Endurance: 100,000 Write/Erase Cycles
 - 512 Bytes Internal SRAM
 - Programming Lock for Software Security
- Peripheral Features
 - Two 8-bit Timer/Counters with Separate Prescalers and Compare Modes
 - One 16-bit Timer/Counter with Separate Prescaler, Compare Mode, and Capture Mode
 - Real Time Counter with Separate Oscillator
 - Four PWM Channels
 - 8-channel, 10-bit ADC
 - 8 Single-ended Channels
 - 7 Differential Channels for TQFP Package Only
 - 2 Differential Channels with Programmable Gain at 1x, 10x, or 200x for TQFP Package Only
 - Byte-oriented Two-wire Serial Interface
 - Programmable Serial USART
 - Master/Slave SPI Serial Interface
 - Programmable Watchdog Timer with Separate On-chip Oscillator
 - On-chip Analog Comparator
- Special Microcontroller Features
 - Power-on Reset and Programmable Brown-out Detection
 - Internal Calibrated RC Oscillator
 - External and Internal Interrupt Sources
 - Six Sleep Modes: Idle, ADC Noise Reduction, Power-save, Power-down, Standby and Extended Standby
- I/O and Packages
 - 32 Programmable I/O Lines
 - 40-pin PDIP, 44-lead TQFP, 44-lead PLCC, and 44-pad MLF
- Operating Voltages
 - 2.7 - 5.5V for ATmega8535L
 - 4.5 - 5.5V for ATmega8535
- Speed Grades
 - 0 - 8 MHz for ATmega8535L
 - 0 - 16 MHz for ATmega8535



8-bit AVR[®] Microcontroller with 8K Bytes In-System Programmable Flash

ATmega8535
ATmega8535L

Advance
Information

Summary

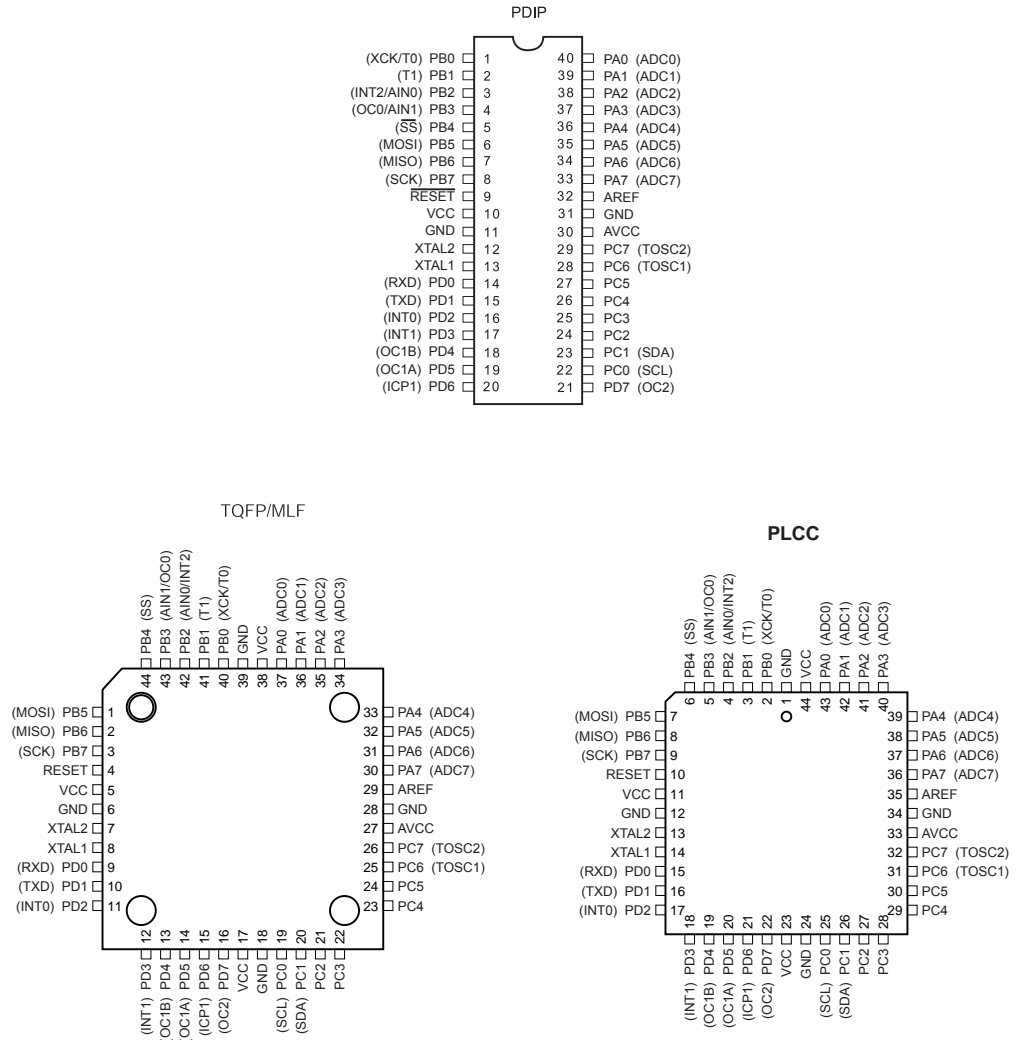
Rev. 2502CS-AVR-04/03



Note: This is a summary document. A complete document is available on our web site at www.atmel.com.

Pin Configurations

Figure 1. Pinout ATmega8535



Disclaimer

Typical values contained in this data sheet are based on simulations and characterization of other AVR microcontrollers manufactured on the same process technology. Min and Max values will be available after the device is characterized.



MOTOROLA

Order this document by ULN2803/D

Octal High Voltage, High Current Darlington Transistor Arrays

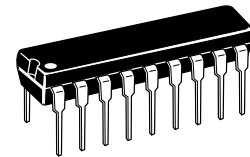
The eight NPN Darlington connected transistors in this family of arrays are ideally suited for interfacing between low logic level digital circuitry (such as TTL, CMOS or PMOS/NMOS) and the higher current/voltage requirements of lamps, relays, printer hammers or other similar loads for a broad range of computer, industrial, and consumer applications. All devices feature open-collector outputs and free wheeling clamp diodes for transient suppression.

The ULN2803 is designed to be compatible with standard TTL families while the ULN2804 is optimized for 6 to 15 volt high level CMOS or PMOS.

ULN2803 ULN2804

OCTAL PERIPHERAL DRIVER ARRAYS

SEMICONDUCTOR TECHNICAL DATA



A SUFFIX
PLASTIC PACKAGE
CASE 707

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ and rating apply to any one device in the package, unless otherwise noted.)

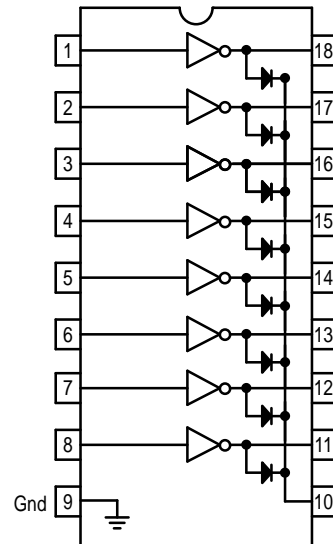
Rating	Symbol	Value	Unit
Output Voltage	V_O	50	V
Input Voltage (Except ULN2801)	V_I	30	V
Collector Current – Continuous	I_C	500	mA
Base Current – Continuous	I_B	25	mA
Operating Ambient Temperature Range	T_A	0 to +70	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$
Junction Temperature	T_J	125	$^\circ\text{C}$

$R_{\theta JA} = 55^\circ\text{C/W}$
Do not exceed maximum current limit per driver.

ORDERING INFORMATION

Device	Characteristics		
	Input Compatibility	$V_{CE}(\text{Max})/I_C(\text{Max})$	Operating Temperature Range
ULN2803A ULN2804A	TTL, 5.0 V CMOS 6 to 15 V CMOS, PMOS	50 V/500 mA	$T_A = 0 \text{ to } +70^\circ\text{C}$

PIN CONNECTIONS



ULN2803 ULN2804

ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Output Leakage Current (Figure 1) (V _O = 50 V, T _A = +70°C) (V _O = 50 V, T _A = +25°C) (V _O = 50 V, T _A = +70°C, V _I = 6.0 V) (V _O = 50 V, T _A = +70°C, V _I = 1.0 V)	All Types All Types ULN2802 ULN2804	I _{CEX}	–	–	100 50 500 500	μA
Collector–Emitter Saturation Voltage (Figure 2) (I _C = 350 mA, I _B = 500 μA) (I _C = 200 mA, I _B = 350 μA) (I _C = 100 mA, I _B = 250 μA)	All Types All Types All Types	V _{CE(sat)}	–	1.1 0.95 0.85	1.6 1.3 1.1	V
Input Current – On Condition (Figure 4) (V _I = 17 V) (V _I = 3.85 V) (V _I = 5.0 V) (V _I = 12 V)	ULN2802 ULN2803 ULN2804 ULN2804	I _{I(on)}	–	0.82 0.93 0.35 1.0	1.25 1.35 0.5 1.45	mA
Input Voltage – On Condition (Figure 5) (V _{CE} = 2.0 V, I _C = 300 mA) (V _{CE} = 2.0 V, I _C = 200 mA) (V _{CE} = 2.0 V, I _C = 250 mA) (V _{CE} = 2.0 V, I _C = 300 mA) (V _{CE} = 2.0 V, I _C = 125 mA) (V _{CE} = 2.0 V, I _C = 200 mA) (V _{CE} = 2.0 V, I _C = 275 mA) (V _{CE} = 2.0 V, I _C = 350 mA)	ULN2802 ULN2803 ULN2803 ULN2803 ULN2804 ULN2804 ULN2804 ULN2804	V _{I(on)}	–	–	13 2.4 2.7 3.0 5.0 6.0 7.0 8.0	V
Input Current – Off Condition (Figure 3) (I _C = 500 μA, T _A = +70°C)	All Types	I _{I(off)}	50	100	–	μA
DC Current Gain (Figure 2) (V _{CE} = 2.0 V, I _C = 350 mA)	ULN2801	h _{FE}	1000	–	–	–
Input Capacitance		C _I	–	15	25	pF
Turn–On Delay Time (50% E _I to 50% E _O)		t _{on}	–	0.25	1.0	μs
Turn–Off Delay Time (50% E _I to 50% E _O)		t _{off}	–	0.25	1.0	μs
Clamp Diode Leakage Current (Figure 6) (V _R = 50 V)	T _A = +25°C T _A = +70°C	I _R	–	–	50 100	μA
Clamp Diode Forward Voltage (Figure 7) (I _F = 350 mA)		V _F	–	1.5	2.0	V